Atty Docket No. NSC1-M3500 [P05681]

DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

inventor (if plural n the invention entitle	ames are listed below) of the	r (if only one name is listed below) or an orig e subject matter which is claimed and for which	inal, first and joi ch a patent is sc	nt ought on
A METHOD OF PA LIKE PULSES OF	MOS STACKED-GATE MEM CONTROL GATE VOLTAGE	ORY CELL PROGRAMMING ENHANCEME	NT UTILIZING S	STAIR-
the specification of was amended on _	which (check one) 🛚 is atta (if applicable).	ched hereto or was filed on as App	olication No	and
l hereby state that claims, as amende	I have reviewed and understand by any amendment referre	and the contents of the above-identified spec d to above.	ification, includi	ng the
I acknowledge the	duty to disclose all informatio	on which is material to patentability as defined	d in 37 CFR § 1	.56.
or inventor's certific than the United Sta	cate, or § 365(a) of any PCT ates, listed below and have al	U.S.C. § 119(a)-(d) or § 365(b) of any foreig International application which designated at Iso identified below any foreign application fo application on which priority is claimed:	least one count	try other
Prior Foreign Appli	cation(s)		Priority (Claimed <u>No</u>
Number	Country	Day/Month/Year Filed		
Number ·	Country	Day/Month/Year Filed		
l hereby claim the t	penefit under 35 U.S.C. § 119	9(3) of any United States provisional applicati	on(s) below:	
Application Numbe	r	Filing Date		-
Application Number	7	Filing Date		-
Application Number	7	Filing Date		-

I hereby claim the benefit under 35 U.S.C. § 120 of any United States application(s), or § 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of 35 U.S.C. § 112, I acknowledge the duty to disclose all information which is material to patentability as defined in 37 CFR § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

Application Number	Filing Date	Status: Patented, Pending, Abandoned
Application Number	Filing Date	Status: Patented, Pending, Abandoned
Application Number	Filing Date	Status: Patented, Pending, Abandoned

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment or both, under 18 U.S.C. § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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	Date
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